RoHS

COMPLIANT

HALOGEN

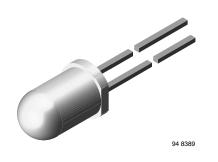
GREEN

(5-2008)



**Vishay Semiconductors** 

# High Power Infrared Emitting Diode, 940 nm, GaAlAs, MQW



#### DESCRIPTION

TSAL6400 is an infrared, 940 nm emitting diode in GaAlAs multi quantum well (MQW) technology with high radiant power and high speed

molded in a blue-gray plastic package.

#### FEATURES

- · Package type: leaded
- Package form: T-1<sup>3</sup>⁄<sub>4</sub>
- Dimensions (in mm): Ø 5
- Peak wavelength:  $\lambda_p = 940 \text{ nm}$
- High reliability
- High radiant power
- High radiant intensity
- Angle of half intensity:  $\phi = \pm 25^{\circ}$
- · Low forward voltage
- Suitable for high pulse current operation
- · Good spectral matching with Si photodetectors
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **APPLICATIONS**

- Infrared remote control units with high power requirements
- Free air transmission systems
- Infrared source for optical counters and card readers

# PRODUCT SUMMARY COMPONENT Ie (mW/sr) φ (deg) λp (nm) tr (ns) TSAL6400 50 ± 25 940 15

#### Note

Test conditions see table "Basic Characteristics"

### **ORDERING INFORMATION**

UNDERING INFORMATION						
ORDERING CODE	PACKAGING REMARKS		PACKAGE FORM			
TSAL6400	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾			

#### Note

• MOQ: minimum order quantity

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Reverse voltage		V <sub>R</sub>	5	V		
Forward current		I <sub>F</sub>	100	mA		
Peak forward current	$t_p/T = 0.5, t_p = 100 \ \mu s$	I <sub>FM</sub>	200	mA		
Surge forward current	t <sub>p</sub> = 100 μs	I <sub>FSM</sub>	1.5	A		
Power dissipation		Pv	160	mW		
Junction temperature		Тj	100	°C		
Operating temperature range		T <sub>amb</sub>	-40 to +85	°C		
Storage temperature range		T <sub>stg</sub>	-40 to +100	°C		
Soldering temperature	$t \le 5$ s, 2 mm from case	T <sub>sd</sub>	260	°C		
Thermal resistance junction/ambient	J-STD-051, leads 7 mm soldered on PCB	R <sub>thJA</sub>	230	K/W		

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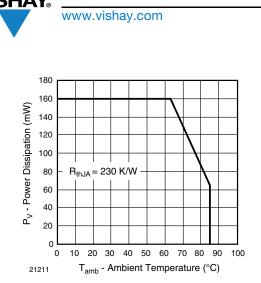


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

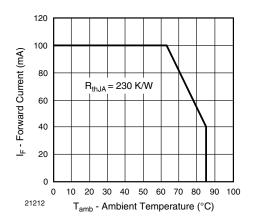


Fig. 2 - Forward Current Limit vs. Ambient Temperature

<b>BASIC CHARACTERISTICS</b> ( $T_{amb} = 25 \text{ °C}$ , unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Forward voltage	I <sub>F</sub> = 100 mA, t <sub>p</sub> = 20 ms	V <sub>F</sub>		1.35	1.6	V	
	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	V <sub>F</sub>		2.2	3	V	
Temperature coefficient of V <sub>F</sub>	$I_F = 1 \text{ mA}$	TK <sub>VF</sub>		-1.8		mV/K	
Reverse current	V <sub>R</sub> = 5 V	I <sub>R</sub>			10	μA	
Junction capacitance	$V_{R} = 0 V, f = 1 MHz, E = 0$	Cj		40		pF	
Dedient intensity	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l <sub>e</sub>	25	50	125	mW/sr	
Radiant intensity	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	l <sub>e</sub>	220	420		mW/sr	
Radiant power	I <sub>F</sub> = 100 mA, t <sub>p</sub> = 20 ms	\$e		40		mW	
Temperature coefficient of $\phi_{e}$	I <sub>F</sub> = 20 mA	ΤKφ <sub>e</sub>		-0.6		%/K	
Angle of half intensity		φ		± 25		deg	
Peak wavelength	I <sub>F</sub> = 100 mA	λρ		940		nm	
Spectral bandwidth	I <sub>F</sub> = 100 mA	Δλ		30		nm	
Temperature coefficient of $\lambda_p$	I <sub>F</sub> = 100 mA	ΤΚλρ		0.2		nm/K	
Rise time	I <sub>F</sub> = 100 mA	t <sub>r</sub>		15		ns	
Fall time	I <sub>F</sub> = 100 mA	t <sub>f</sub>		15		ns	



## **Vishay Semiconductors**

## **BASIC CHARACTERISTICS** ( $T_{amb}$ = 25 °C, unless otherwise specified)

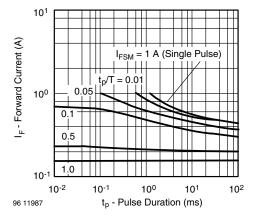


Fig. 3 - Pulse Forward Current vs. Pulse Duration

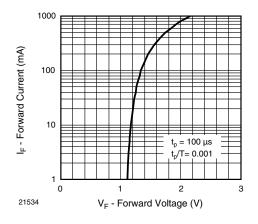


Fig. 4 - Forward Current vs. Forward Voltage

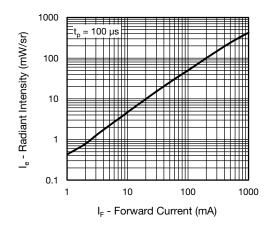


Fig. 5 - Radiant Intensity vs. Forward Current

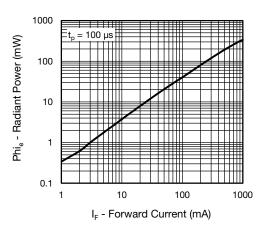


Fig. 6 - Radiant Power vs. Forward Current

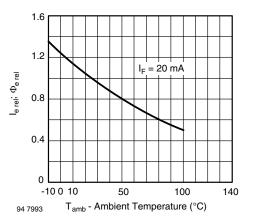


Fig. 7 - Relative Radiant Intensity/Power vs. Ambient Temperature

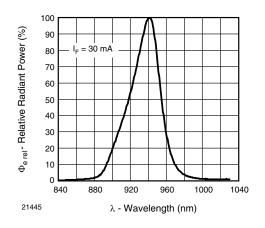


Fig. 8 - Relative Radiant Power vs. Wavelength

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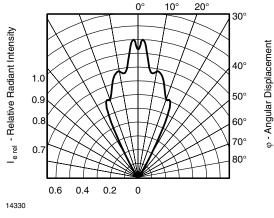
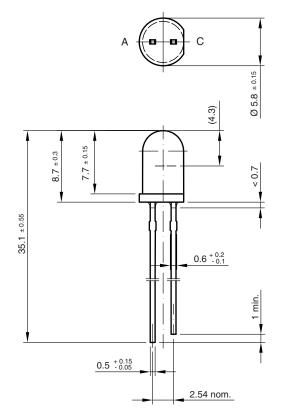
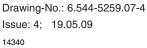
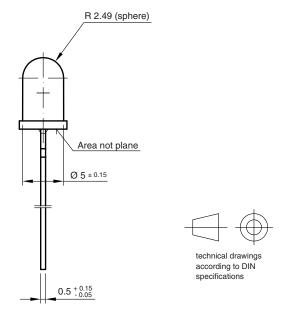


Fig. 9 - Relative Radiant Intensity vs. Angular Displacement









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